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# Magnetic dephasing in mesoscopic spin glasses

Thibaut Capron<sup>1</sup>, Guillaume Forestier<sup>1</sup>, Angela Perrat-Mabilon<sup>2</sup>, Christophe Peaucelle<sup>2</sup>, Tristan Meunier<sup>1</sup>, Christopher Bäuerle<sup>1</sup>, Laurent P. Lévy<sup>1,4,5</sup>, David Carpentier<sup>3</sup> and Laurent Saminadayar<sup>1,4,5,†</sup>

<sup>1</sup>*Institut Néel, B.P. 166, 38042 Grenoble Cedex 09, France*

<sup>2</sup>*Institut de Physique Nucléaire de Lyon, Université de Lyon 1, CNRS & IN2P3, 04 rue Enrico Fermi, 69622 Villeurbanne Cedex, France*

<sup>3</sup>*Laboratoire de Physique, École Normale Supérieure de Lyon, 47 allée d'Italie, 69007 Lyon, France*

<sup>4</sup>*Université Joseph Fourier, B.P. 53, 38041 Grenoble Cedex 09, France and*

<sup>5</sup>*Institut Universitaire de France, 103 boulevard Saint-Michel, 75005 Paris, France*

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We have measured Universal Conductance Fluctuations in the metallic spin glass  $Ag : Mn$  as a function of temperature and magnetic field. From this measurement, we can access the phase coherence time of the electrons in the spin glass. We show that this phase coherence time increases with both the inverse of the temperature and the magnetic field. From this we deduce that decoherence mechanisms are still active even deep in the spin glass phase.

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Spin glasses are one of the most fascinating states of matter. It has attracted the interest of a large community for several decades, as it is one of the most fundamental problems in Condensed Matter Physics [2]. Spin Glass appears when magnetic atoms are randomly diluted in a non-magnetic metallic host. As the spatial distribution is random, so are the RKKY interactions between the spins. This leads to a frustration between the magnetic moments and their couplings. It is this interplay between disorder and frustration that leads to the formation of a *spin glass* below a transition temperature  $T_{sg}$ . The very nature of the ground state is still heavily debated and may consist in an unconventional state of matter with remarkable behavior [3]. Transport properties of these metallic spin glasses, however, have not been studied thoroughly. In particular, only very few studies, experimental or theoretical, have addressed the question of the quantum coherence of the electrons in a metallic spin glass, and it is usually taken for granted that, as spins are frozen, inelastic scattering processes due to spins are also frozen and one should recover the coherence time observed in a Fermi liquid.

It has been widely recognized that transport measurement can be a powerful tool to probe the quantum coherence in metallic systems [4], and that this concept can be extended to spin glasses [5]. Recently, the interest in quantum transport measurements in spin glasses has been even renewed thanks to the idea that this type of measurements could give access to the structure of the ground state of the system [6].

In this Letter, we present measurements of Universal Conductance Fluctuations (UCFs) in a metallic spin glass as a function of temperature and magnetic field. From this we deduce the phase coherence time of the electrons; we show it increases as the temperature decreases, in agreement with theoretical predictions. Moreover, from the magnetic field dependence of the decoherence rate,

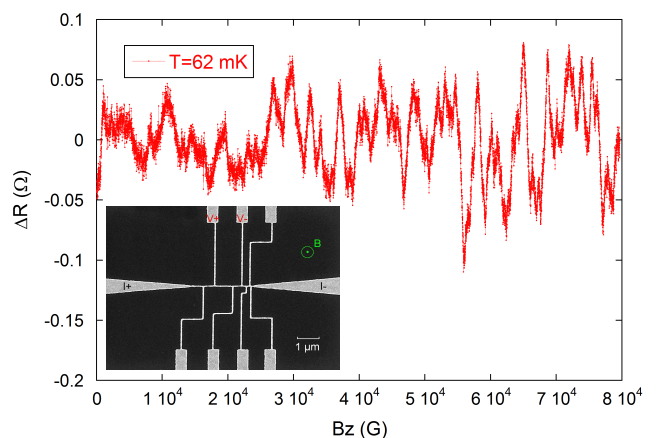


FIG. 1. (Color online) Magnetoresistance of a spin glass  $Ag$  sample implanted with 700 ppm of manganese. The magnetic field is applied perpendicularly to the sample. Insert: Scanning Electron Microscopy of the sample; current and voltage probes are indicated in red.

we show that decoherence mechanisms persist deep in the spin glass phase.

Samples have been fabricated on a silicon/silicon oxide wafer using standard electron-beam lithography on polymethyl-methacrylate (PMMA) resist. Geometry of the sample consists in a long (length  $L \approx 2 \mu\text{m}$ ) and thin (width  $w \approx 50 \text{ nm}$ , thickness  $t \approx 40 \text{ nm}$ ) wire (see inset of figure 1). Several contacts have been put along the wire, in order to measure the resistance over different lengths and to thermalize properly the electrons along the wire. Silver has been evaporated using a dedicated electron gun evaporator and a 99.9999% purity source without adhesion layer. Electronic properties of pure samples fabricated during the same run have been measured in previous works [7, 8], leading to the values  $l_e = 43 \text{ nm}$  for the elastic mean free path,  $\rho = 2.15 \mu\Omega \cdot \text{cm}$  for the resistiv-

ity and  $L_\phi = 7 \mu\text{m}$  for the phase coherence length at low temperature (below  $\approx 50 \text{ mK}$ ). Samples have then been implanted with  $Mn^{2+}$  ions of energy  $70 \text{ keV}$ . The energy has been chosen after numerical simulations based on the SRIM software in order to ensure that ions will end up in the sample following a gaussian distribution whose maximum lies in the middle of the sample thickness. Moreover, this technique of implantation allows to avoid clustering or migration of the  $Mn^{2+}$  ions as no further annealing has been performed on the samples. The ion dose, measured *via* the current of the implanter, has been chosen in order to give a final ion concentration in the wire of  $700 \text{ ppm}$ ; such a concentration leads to a transition temperature of  $T_{sg} \approx 700 \text{ mK}$ , as has been demonstrated recently by transport measurements [8]: it is thus easy to perform measurements well below  $T_{sg}$ . The sample has been cooled down in a dilution fridge

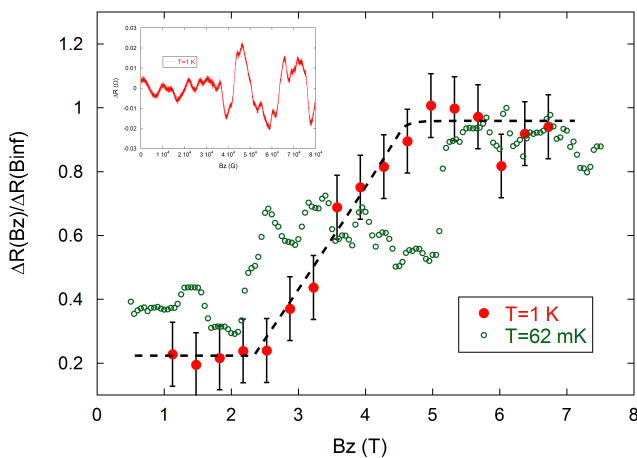


FIG. 2. (Color online) Relative amplitude of the Universal Conductance Fluctuations as a function of the magnetic field. The inset shows that this increase is already clear on the direct magnetoresistance trace.

whose base temperature  $T$  is  $\approx 50 \text{ mK}$  and equipped with a superconducting coil of maximum magnetic field  $B = 8 \text{ T}$ . Transport measurements have been carried out using an ac lock-in technique at a frequency of  $11 \text{ Hz}$  in a bridge configuration and using a very low current of  $250 \text{ nA}$ , in order to avoid any over heating of the sample. Signal is amplified using an ultra-low noise homemade voltage amplifier (voltage noise  $S_v = 500 \text{ pV}/\sqrt{\text{Hz}}$ ) at room temperature. All the measuring lines connecting the sample to the experimental set-up consist in lossy coaxies which ensure a very efficient radio-frequency filtering and thus a good thermalization of the sample [9–11]. At  $4.2 \text{ K}$ , the resistance of our sample is  $R \approx 10 \Omega$ .

Universal Conductance Fluctuations are obtained by measuring the magnetoresistance of the sample between  $0 \text{ T}$  and  $8 \text{ T}$ . The field is swept at a rate of  $20 \text{ mG/s}$  in order to avoid excessive eddy-currents heating of the fridge. After subtraction of the classical magnetoresis-

tance of a spin glass [12–14], one clearly sees the UCFs as shown on figure 1. These magnetoresistance traces are decorrelated by a temperature cycling well over  $T_{sg}$ , signaling the coupling of this magnetoresistance to the frozen spins. On the other hand it should be stressed that they are completely reproducible over the sweeping direction. Moreover, we observe that the maximum magnetic field applied is much larger than the expected critical field,  $B \gg B_c = k_B T_{sg}/\mu_B$  with  $\mu_B$  the Bohr magneton and  $k_B$  the Boltzmann constant. Such a result is similar to what has been observed in the work of Lévy *et al.* on a  $\text{Cu} : \text{Mn}$  system [5]: *the exact spin configuration of a spin glass is preserved after a magnetic cycling to very high magnetic field at a temperature of  $\approx T_{sg}/10$ .* Within the mean-field phase diagram of spin glasses two critical lines exist related to the freezing of longitudinal component (“de Almeida-Thouless” line) and transverse component of the spins (“Gabay-Toulouse” line). While magnetization measurements usually probe the longitudinal freezing and observe a freezing field of the order  $B_c$ , transport measurements are sensitive to the freezing of both components of the spins. Similarly, this transverse freezing has also been probed in torque experiments as reported in [23]. Remarkably, both experiments signal much stronger freezing field than the expected  $B_c$ . Whether this finding is compatible with the chiral freezing scenario of Kawamura *et al.* [24] is an interesting although open question.

We now consider the *amplitude* of these UCFs as a function of the magnetic field; for this purpose, we have plotted on figure 2 the peak-to-peak amplitude (extracted from the inset of the figure) as a function of the magnetic field. Two regimes are clearly visible: a low field regime (typically below  $B \lesssim 2.5 \text{ T}$ ) and a high field regime ( $B \gtrsim 4.5 \text{ T}$ ) regimes. They differ by the amplitude of the UCFs which is *5 times larger* in the high field regime. Such an increase of the amplitude of the UCFs manifests an increase of  $L_\phi$  [18]. More precisely as long as the phase coherence length of the electrons  $L_\phi$  is smaller than both the system length and the thermal length  $L_\phi \leq L_T, L$ , the amplitude of the UCFs scale as  $\Delta G_{\text{UCFs}} \propto (L_\phi/L)^{3/2}$ . In this regime, an increase of the UCF manifests the corresponding increase of dephasing length. On the other hand, for  $L_T \leq L_\phi \leq L$  the UCFs amplitude saturates to  $\Delta G_{\text{UCFs}} \propto (L_T/L)$  and becomes independent of  $L_\phi$ . The results of figure 2 are thus interpreted as an increase of the dephasing length  $L_\phi$  up to a magnetic field  $B \simeq 4.5 \text{ T}$ , until this dephasing length reaches the thermal length  $L_\phi \simeq L_T$  or system size  $L_\phi \simeq L$  for  $B \simeq 4.5 \text{ T}$ . Below, we will relate this increase of dephasing length to a change of magnetic dephasing due to the polarization of the ensemble of magnetic impurities. The scale in magnetic field on which this polarization occurs is governed by the typical amplitude  $J_{\text{RKKY}}$  of the couplings between impurity spins. The magnetization of  $\text{Cu} : \text{Mn}$  bulk spin glass with an  $Mn$  concentration in the range  $1 - 10 \%$  in

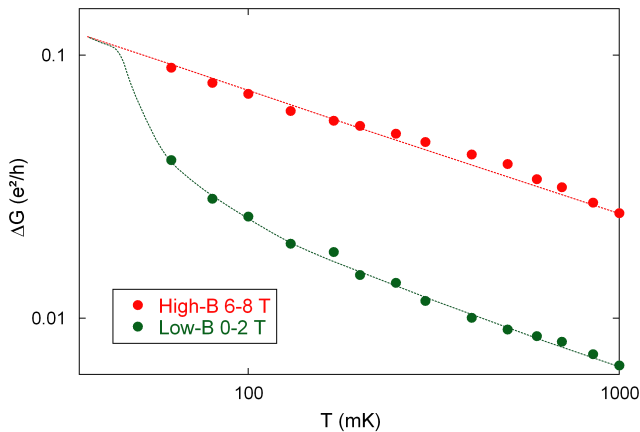


FIG. 3. (Color online) Amplitude of the UCFs as a function of temperature, for high field ( $B \geq 6T$ ) and low field ( $B \leq 2T$  field). Note that the “high” field curve follows nicely a power law, whereas the “low” field curve tends to join it at very low temperature. Dotted lines are guides for the eyes.

high field up to  $40T$  shows a progressive saturation with field [25]. Rescaling these data by the impurity concentration we infer a saturating field of  $2.5T$  for our  $700\text{ ppm } Ag : Mn$  sample, compatible with the data represented on figure 2. We now focus on the low and intermediate field regimes. For the range of parameters explored here, the electron-phonons and electron-electron mechanism are subdominant and the dephasing rate  $1/\tau_\phi$  is dominated by the electron-magnetic impurities processes [7],  $1/\tau_\phi \simeq 1/\tau_{e-s}$ . We thus focus on the magnetic dephasing rate, and its evolution with magnetic field and temperature. We account for the strong couplings between the magnetic impurities through an effective field description [22]. In this description, the spin  $\vec{S}_i$  of each magnetic impurity is submitted to a effective magnetic field  $\vec{h}_i$  originating from both the competing RKKY couplings to the neighboring spins and from the external magnetic field  $\vec{B}$ . At each temperature and magnetic field, the spin glass state is thus described by a distribution of effective fields  $P_{T,\vec{B}}(\vec{h}_i)$  over the various impurities. Each impurity is thus treated independently of the others. The corresponding magnetic dephasing can be described using the Kondo dephasing mechanism [7, 16, 19]. Two different dephasing mechanisms occur depending on the strength of the effective field  $|\vec{h}_i|$ : for the effective “free spins” for which  $g\mu_B|\vec{h}_i| \leq kT$ , the dominant dephasing mechanism is the usual Kondo dephasing [7, 16, 19] with a rate [17]

$$\frac{1}{\tau_{e-s}^{free}} = \frac{8\pi n_{imp}^{free}}{\rho(E_F)} \frac{S(S+1)}{\ln^2 T/T_K} \quad (1)$$

where

$$n_{imp}^{free} \simeq n_{imp} P_{T,B}(h=0) \frac{k_B T}{g\mu_B} \quad (2)$$

is the concentration of these effective free spins. For the other spins (such that  $g\mu_B|\vec{h}_i| \geq kT$ ), the dephasing occurs *via* a different virtual process mechanism with a rate

$$\frac{1}{\tau_{e-s}^{pol}} \simeq \frac{n_{imp}^{pol}}{\tau_{Kondo}(B)} \quad (3)$$

with  $\tau_{Kondo}(B) \propto B$  [17]. Note that this virtual process is much less efficient than the direct process described in equation (1). When both are present, virtual processes are thus negligible: this corresponds to the low-field regime of figure 2. The plateau of  $\Delta R$  in this regime hints that the probability  $P_{T,B}(h=0)$  varies slowly over this magnetic field range. The change of behavior at  $B \simeq 2.5T$  indicates the disappearance of the direct Kondo dephasing. Beyond this field, all impurities contribute to the dephasing through the virtual process mechanism (eq. 2). In this regime,  $\tau_\phi$  is proportional to  $B$  (equation 3) leading to an amplitude of the UCFs scaling as  $\Delta R \propto L_\phi^{3/2} \simeq B^{3/4}$ , in good agreement with our experimental data (figure 2).

On figure 3, we have plotted the amplitude of the UCFs for both high and low magnetic field, as a function of temperature. The high field ( $B \geq 6T$ ) amplitude is found to scale as  $\Delta G_{UCFs} \propto T^{-1/2}$ . This scaling is compatible with our previous analysis using  $L_T = (\hbar D/T)^{1/2} \simeq T^{-1/2}$ . To analyze quantitatively the low field regime ( $B \leq 2T$ ), we extract the phase coherence time  $\tau_\phi$  from the amplitude of the UCFs and then subtract the Al’tshuler-Aronov-Khmelnitsky (AAK) [26]: this provides the (dominant) magnetic dephasing rate. Its temperature dependence is depicted on figure 4. Using equation (1), and neglecting the  $\ln^2 T/T_K$  when  $T \gg T_K$ , we can extract the temperature dependence of the fraction of free spins,  $n_{imp}^{free}/n_{imp}$ . The result is shown on figure 5. Note, however, that above  $1K$ , the data are not reliable as the (neglected) electron-phonon scattering starts to play a non-negligible role in the decoherence processes. The obtained temperature dependence is compatible with  $n_{imp}^{free}/n_{imp} \propto T^\alpha$  with  $\alpha$  close to 1. We can extract the temperature scaling behavior of the probability  $P_{T,B}(h_i=0) \propto T^{\alpha-1}$  using equation 2. The experimental data are compatible with either a constant probability ( $\alpha = 1$ ) or a weak pseudo-gap behavior ( $\alpha \geq 1$ ) [22].

What can we infer from these measurements? In our system, both the implantation concentration as well as remanent effect indicate a freezing temperature of  $\approx 700\text{ mK}$  [8]. It is commonly believed that slightly below  $T_{sg}$  (almost) all the spins are completely frozen. Mesoscopic probes, which have so far not been exploited in the field of spin glasses, demonstrate that this is actually not the case: even at low temperature (one tenth of  $T_{sg}$ ), almost 10% of the spins are still free to flip by thermal activation. This shows that the spin glass transition is indeed very broad, a total freezing of all the

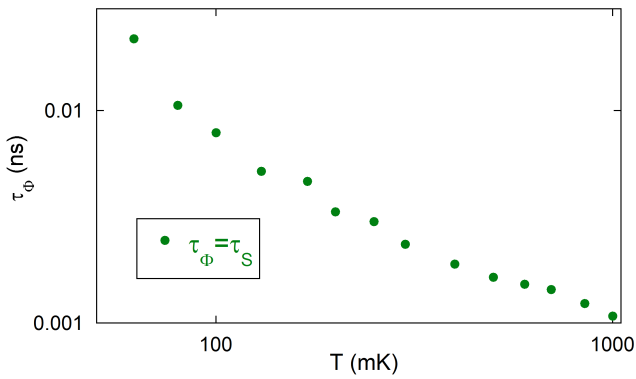


FIG. 4. (Color online) Decoherence rate as a function of temperature extracted from the low field curve of the figure 3.

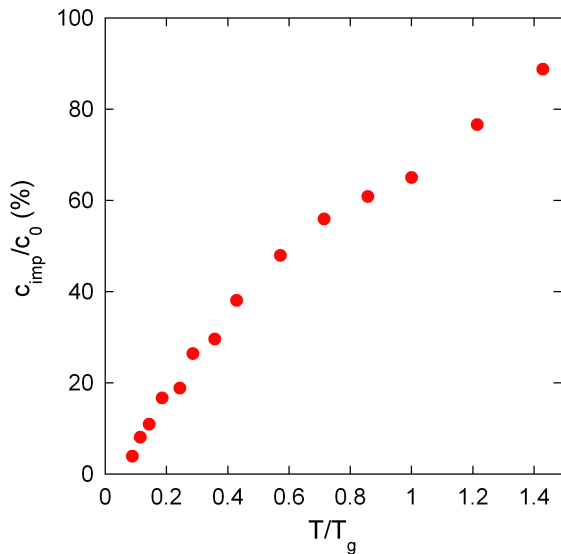


FIG. 5. (Color online) Fraction of free spins (normalized to the initial concentration of magnetic impurities) as a function of the normalized temperature (normalized to the freezing temperature  $T_{sg}$ ).

spins appearing only below  $T_{sg}/10$ . Moreover, even at low temperature and below the characteristic field  $B_c$ , a finite fraction of the spins remains actually free.

To conclude, we have measured phase coherent transport in an  $Ag : Mn$  spin glass doped at a level of 700 ppm. We have shown that the Universal Conductance Fluctuations are perfectly reproducible up to a field of  $8T$ , i.e. a field much larger than the characteristic field  $B_c \approx k_B T_{sg} / \mu_B$ . Moreover, we observe a strong increase of the amplitude of these UCFs above a field of  $2.5T$ ; this increase is interpreted as an increase of the phase coherence length due to the polarization of the spins. Finally, we describe the gradual freezing of the

spins when lowering the temperature. This constitutes the first experimental probe of the fraction of free spins in a spin glass using mesoscopic transport measurements. This study paves the way for a measurement of the overlaps between microscopic spin configuration in the spin glass phase [27].

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- [†] Mail to: [saminadayar@grenoble.cnrs.fr](mailto:saminadayar@grenoble.cnrs.fr)
  - [2] Complex systems, Les Houches summer school, Vol. LLXXXV, J.-P. Bouchaud, M. Mézard and J. Dalibard eds., Springer Verlag (2006).
  - [3] É. Vincent *et al.*, J. Stat. Phys. **135**, 1105 (2009).
  - [4] F. Schopfer *et al.*, Phys. Rev. Lett. **90**, 056801 (2003).
  - [5] P. G. N. de Vegvar *et al.*, Phys. Rev. Lett. **66**, 2380 (1991).
  - [6] D. Carpentier and É. Orignac, Phys. Rev. Lett. **100**, 057207 (2008).
  - [7] F. Mallet *et al.*, Phys. Rev. Lett. **97**, 226804 (2006).
  - [8] T. Capron *et al.*, Europhys. Lett. **93**, 27001 (2011).
  - [9] A. B. Zorin, Rev. Sci. Instrum. **66**, 4296 (1995).
  - [10] D. C. Glatthli *et al.*, J. Appl. Phys. **81**, 7350 (1997).
  - [11] S. Mandal *et al.*, Rev. Sci. Instrum. **82**, 024704 (2011).
  - [12] O. Laborde and P. Radhakrishna, Sol. State Com. **9**, 701 (1971).
  - [13] J. A. Mydosh *et al.*, Phys. Rev. B **10**, 2845 (1974).
  - [14] U. Larsen, Phys. Rev. B **14**, 4356 (1976).
  - [15] A. K. Nigam and A. K. Majumbar, Phys. Rev. B **27**, 495 (1983).
  - [16] L. Saminadayar *et al.*, Physica E **40**, 12 (2007).
  - [17] M. G. Vavilov and L. I. Glazman, Phys. Rev. B **67**, 115310 (2003).
  - [18] É. Akkermans and G. Montambaux, *Mesoscopic physics of electrons and photons*, Cambridge University Press, Cambridge, (2007).
  - [19] C. Bäuerle *et al.*, Phys. Rev. Lett. **95**, 266805 (2005).
  - [20] G. M. Alzoubi and N. O. Birge, Phys. Rev. Lett. **97**, 226803 (2006).
  - [21] T. A. Costi *et al.*, Phys. Rev. Lett. **102**, 056802 (2006).
  - [22] S. Boettcher *et al.*, J. Phys. A: Math. Theor. **41** 324007 (2008).
  - [23] D. Petit *et al.*, Phys. Rev. Lett. **88** 207206 (2002).
  - [24] H. Kawamura and D. Imagawa, Phys. Rev. Lett. **87**, 207203 (2001).
  - [25] J. J. Smit *et al.*, Sol. State Com. **31**, 265 (1979).
  - [26] B. L. Al'tshuler and A. G. Aronov, in *Electron-Electron Interactions in Disordered Systems*, edited by A. L. Efros and M. Pollak (North-Holland, Amsterdam, 1985).
  - [27] M. Mézard *et al.*, Phys. Rev. Lett. **52** 1156 (1984).